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Electrical Transport and Thermoelectric Properties of SnSe–SnTe Solid Solution

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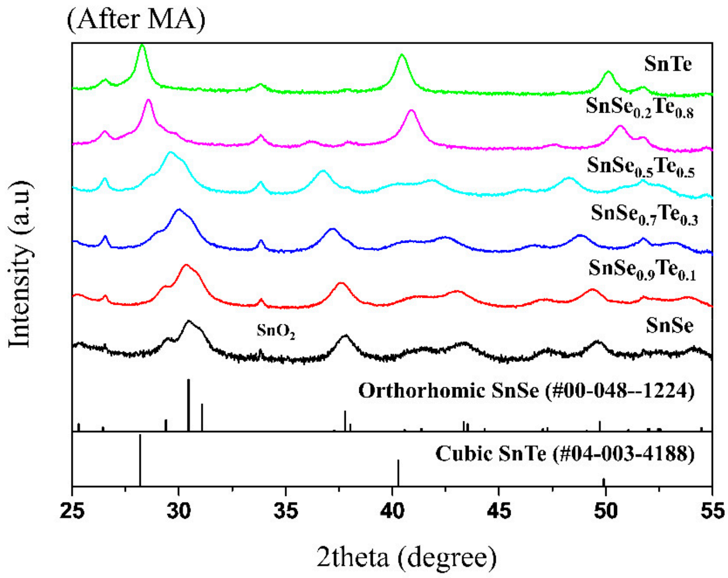

Figure S1. Theta-2theta XRD patterns of the polycrystalline $SnSe_{1-x}Te_x$ (x= 0, 0.1, 0.3, 0.5, 0.8 and 1) powder prepared using mechanical alloying.

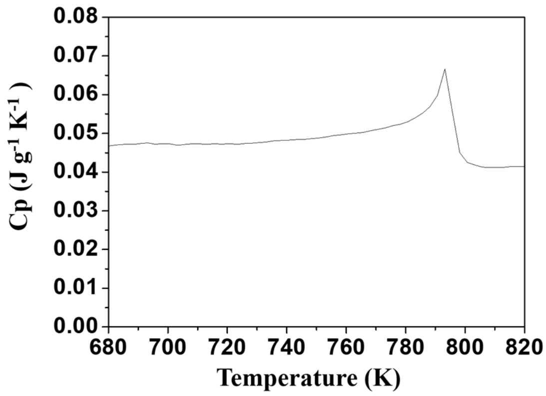

Figure S2. Heat capacity of SnSe measured by differential scanning calorimetry (DSC).

Table S1. The cell parameters of the polycrystalline $SnSe_{1-x}Te_x$ (x = 0, 0.1, 0.3, 0.5, 0.8 and 1) obtained by Rietveld refinement method using TOPAS software.

Sample	Composition	a(Å)	b(Å)	c(Å)	α=β=γ
1	SnSe	11.495	4.152	4.442	90
2	$Sn(Se_{0.9}Te_{0.1})$	11.542	4.183	4.458	90
3	$Sn(Se_{0.7}Te_{0.3})$	11.659	4.227	4.483	90
4	$Sn(Se_{0.5}Te_{0.5})$	11.703	4.251	4.489	90
		6.243	6.243	6.243	90
5	$Sn(Se_{0.2}Te_{0.8})$	6.261	6.261	6.261	90
6	SnTe	6.315	6.315	6.315	90